

## **TSM2N7000**

### 60V N-Channel MOSFET

# Pb Rohs COMPLIANCE

#### SOT-92



#### Pin Definition:

- 1. Gate
- 2. Source
- 3. Drain

#### PRODUCT SUMMARY

V <sub>DS</sub> (V)	$R_{DS(on)}(\Omega)$	I <sub>D</sub> (mA)		
60	5 @ V <sub>GS</sub> = 10V	500		

#### **Features**

- Fast Switching Speed
- Low Input and Output Leakage

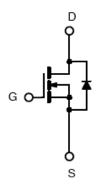
### **Application**

- Direct Logic-Level Interface: TTL/CMOS
- Solid-State Relays

#### **Ordering Information**

Part No.	Package	Packing
TSM2N7000CT B0	TO-92	1Kpcs / Bulk
TSM2N7000CT A3	TO-92	2Kpcs / Ammo

#### **Block Diagram**



N-Channel MOSFET

#### **Absolute Maximum Rating** (Ta = 25°C unless otherwise noted)

Parameter		Symbol	Limit	Unit	
Drain-Source Voltage		V <sub>DS</sub>	60	V	
Gate-Source Voltage		$V_{GS}$	±20	V	
Continuous Drain Current		I <sub>D</sub>	200	mA	
Pulsed Drain Current		I <sub>DM</sub>	500	mA	
Continuous Source Current (Diode C	onduction) <sup>a,b</sup>	I <sub>S</sub>	500	mA	
Maximum Power Dissipation	Ta = 25°C		350	mW	
	Ta = 75°C	P <sub>D</sub>	280		
Operating Junction Temperature		TJ	+150	°C	
Operating Junction and Storage Temperature Range		T <sub>J</sub> , T <sub>STG</sub>	-55 to +150	°C	

#### **Thermal Performance**

Parameter	Symbol	Limit	Unit	
Lead Temperature (1/8" from case)	T <sub>L</sub>	10	S	
Junction to Ambient Thermal Resistance (PCB mounted)	RO <sub>JA</sub>	357	°C/W	

#### Notes:

- a. Pulse width limited by the Maximum junction temperature
- b. Surface Mounted on FR4 Board, t ≤ 5 sec.

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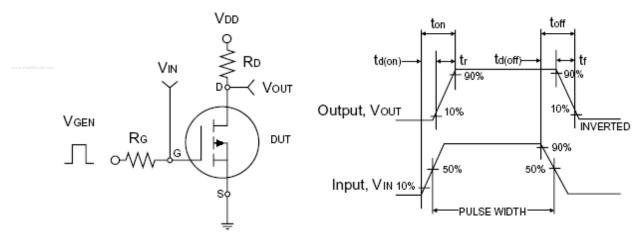
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**Electrical Specifications** (Ta = 25°C, unless otherwise noted)

Parameter	Conditions	Symbol	Min	Тур	Max	Unit
Static				•	•	
Drain-Source Breakdown Voltage	$V_{GS} = 0V, I_D = 10\mu A$	BV <sub>DSS</sub>	60			V
Gate Threshold Voltage	$V_{DS} = V_{GS}$ , $I_D = 1mA$	V <sub>GS(TH)</sub>	8.0		3.0	V
Gate Body Leakage	$V_{GS} = \pm 15V, V_{DS} = 0V$	I <sub>GSS</sub>			±10	nA
Zero Gate Voltage Drain Current	$V_{DS} = 48V, V_{GS} = 0V$	I <sub>DSS</sub>			1.0	μA
Drain Course On State Besistance	$V_{GS} = 10V, I_D = 500mA$	R <sub>DS(ON)</sub>			5.0	Ω
Drain-Source On-State Resistance	$V_{GS} = 5V, I_D = 50mA$			7.5		
Forward Transconductance	$V_{DS} = 15V, I_D = 300 \text{mA}$	g <sub>fs</sub>	-	320		mS
Diode Forward Voltage	I <sub>S</sub> = 200mA, V <sub>GS</sub> = 0V	$V_{SD}$		1.3	1.5	V
Dynamic <sup>b</sup>	•					
Input Capacitance	\/ - 25\/ \/ - 0\/	C <sub>iss</sub>	1	60		
Output Capacitance	$V_{DS} = 25V, V_{GS} = 0V,$	C <sub>oss</sub>		25		pF
Reverse Transfer Capacitance	f = 1.0MHz	C <sub>rss</sub>		5		
Switching <sup>c</sup>						
Turn-On Rise Time	$V_{DD} = 15V, R_{L} = 30\Omega,$	t <sub>r</sub>		10		~ C
Turn-Off Fall Time	$I_D = 500 \text{mA},$ $V_{GEN} = 10 \text{V}, R_G = 25 \Omega$	t <sub>f</sub>		10		nS

#### Notes:

- a. pulse test: PW  $\leq 300 \mu S$ , duty cycle  $\leq 2\%$  b. For DESIGN AID ONLY, not subject to production testing.
- b. Switching time is essentially independent of operating temperature.



**Switching Test Circuit** 

Switchin Waveforms

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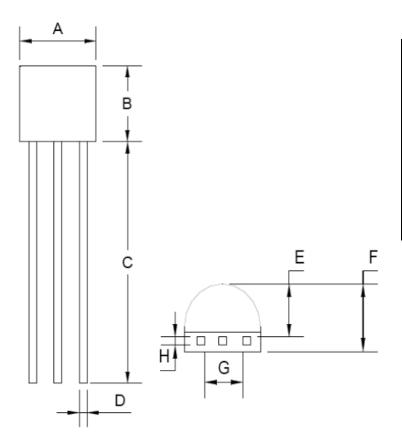


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### **TO-92 Mechanical Drawing**



TO-92 DIMENSION					
DIM	MILLIMETERS		INCHES		
	MIN	MAX	MIN	MAX	
Α	4.30	4.70	0.169	0.185	
В	4.30	4.70	0.169	0.185	
С	14.30(typ)		0.563(typ)		
D	0.43	0.49	0.017	0.019	
Е	2.19	2.81	0.086	0.111	
F	3.30	3.70	0.130	0.146	
G	2.42	2.66	0.095	0.105	
Н	0.37	0.43	0.015	0.017	

3/4 Version: A07



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